NEC

MOS FIELD EFFECT TRANSISTOR μ PA611TA

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR HIGH SPEED SWITCHING

DESCRIPTION

The μ PA611TA is a switching device which can be driven directly by a 2.5-V power source.

The μ PA611TA has excellent switching characteristics, and is suitable for use as a high-speed switching device in digital circuits.

FEATURES

- Can be driven by a 2.5-V power source
- · Low gate cut-off voltage

ORDERING INFORMATION

| PART NUMBER | PACKAGE | |
|-------------|-------------------|--|
| μΡΑ611ΤΑ | SC-74 (Mini Mold) | |

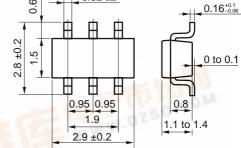
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

| Drain to Source Voltage | Vdss | 30 | V |
|----------------------------|----------|-------------|----|
| Gate to Source Voltage | Vgss | ±20 | V |
| Drain Current (DC) | ID(DC) | ±0.1 | А |
| Drain Current (pulse) Note | D(pulse) | ±0.4 | А |
| Total Power Dissipation | Рт | 300 (TOTAL) | mW |
| Channel Temperature | Tch | 150 | °C |
| Storage Temperature | Tstg | -55 to +150 | °C |

Note PW \leq 10 μ s, Duty Cycle \leq 1 %

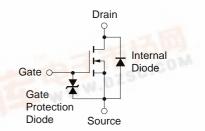


PACKAGE DRAWING (Unit : mm)

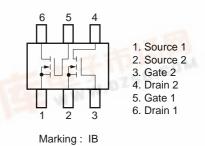


EQUIVALENT CIRCUIT

(1/2 Circuit)



PIN CONNECTION (Top View)



Remark

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

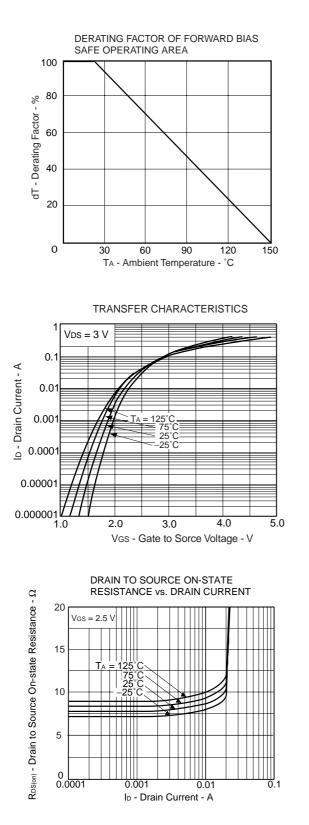
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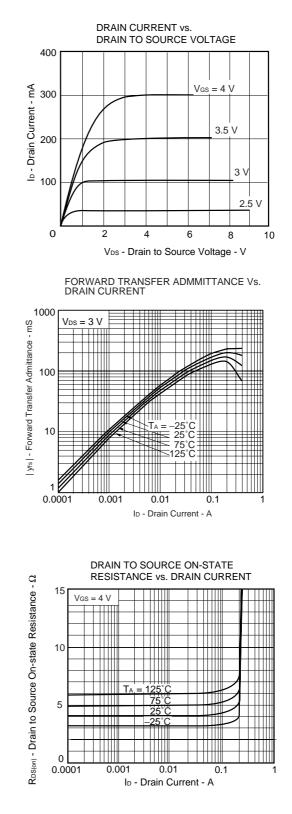


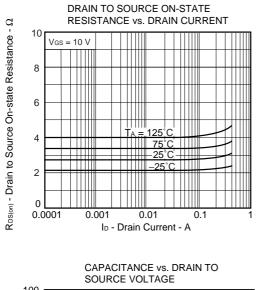
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

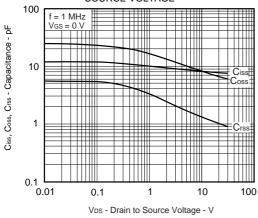
| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------------------------------|-----------------|---|------|------|------|------|
| Drain Cut-off Current | Dss | $V_{DS} = 30 V$, $V_{GS} = 0 V$ | | | 1 | μA |
| Gate Leakage Current | lgss | $V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$ | | | ±10 | μA |
| Gate Cut-off Voltage | VGS(off) | $V_{DS} = 3 V$, $I_D = 10 \mu A$ | 1.0 | 1.4 | 1.8 | V |
| Forward Transfer Admittance | y _{fs} | $V_{DS} = 3 V, I_{D} = 10 m A$ | 20 | | | mS |
| Drain to Source On-state Resistance | RDS(on)1 | Vgs = 2.5 V, Id = 1 m A | | 8 | 15 | Ω |
| | RDS(on)2 | $V_{GS} = 4 V, I_{D} = 10 mA$ | | 4 | 8 | Ω |
| | RDS(on)3 | $V_{GS} = 10 V, I_{D} = 10 mA$ | | 3 | 5 | Ω |
| Input Capacitance | Ciss | V _{DS} = 3 V | | 9 | | pF |
| Output Capacitance | Coss | V _G s = 0 V | | 12 | | pF |
| Reverse Transfer Capacitance | Crss | f = 1 MHz | | 2.1 | | pF |
| Turn-on Delay Time | td(on) | V _{DD} = 3 V | | 40 | | ns |
| Rise Time | tr | ID = 10 mA | | 55 | | ns |
| Turn-off Delay Time | td(off) | V _{GS(on)} = 4 V | | 68 | | ns |
| Fall Time | tr | R _G = 10 Ω, R∟ = 300 Ω | | 64 | | ns |

TYPICAL CHARACTERISTICS (T_A = 25 °C)

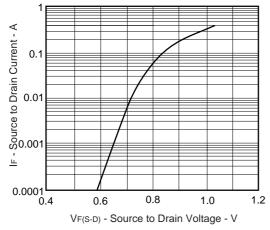


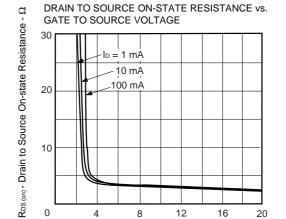




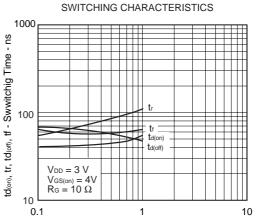








VGS - Gate to Source Voltage - V







REFERENCE

| Document Name | Document No. | | |
|---|--------------|--|--|
| NEC semiconductor device reliability / quality control system | TEI-1202 | | |
| Quality grade on NEC semiconductor devices | C11531E | | |
| Semiconductor device mounting technology manual | C10535E | | |
| Guide to quality assurance for semiconductor devices | MEI-1202 | | |
| Semiconductor selection guide | X10679E | | |

[MEMO]

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- Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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